NPN-Silizium-Fototransistor Silicon NPN Phototransistor Lead (Pb) Free Product - RoHS Compliant

SFH 314 SFH 314 FA





SFH 314 SFH 314 FA

Wesentliche Merkmale

- Speziell geeignet für Anwendungen im Bereich von 460 nm bis 1080 nm (SFH 314) und bei 880 nm (SFH 314 FA)
- Hohe Linearität
- 5 mm-Plastikbauform

Anwendungen

- Computer-Blitzlichtgeräte
- Lichtschranken für Gleich- und Wechsellichtbetrieb
- Industrieelektronik
- "Messen/Steuern/Regeln

Typ Type	Bestellnummer Ordering Code
SFH 314	Q62702P1668
SFH 314-2/3	Q62702P3600
SFH 314 FA	Q62702P1675
SFH 314 FA-2/3	Q62702P3599

Features

- Especially suitable for applications from 460 nm to 1080 nm (SFH 314) and of 880 nm (SFH 314 FA)
- High linearity
- 5 mm plastic package

Applications

- · Computer-controlled flashes
- Photointerrupters
- Industrial electronics
- · For control and drive circuits

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Grenzwerte Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{ m op};T_{ m stg}$	- 40 + 100	°C
Kollektor-Emitterspannung Collector-emitter voltage	$V_{\sf CE}$	70	V
Kollektorstrom Collector current	I_{C}	50	mA
Kollektorspitzenstrom, τ < 10 μ s Collector surge current	I_{CS}	100	mA
Emitter-Kollektorspannung Emitter-collector voltage	V_{EC}	7	V
Verlustleistung, $T_{\rm A}$ = 25 °C Total power dissipation	P _{tot}	200	mW
Wärmewiderstand Thermal resistance	R_{thJA}	375	K/W



Kennwerte ($T_A = 25 \, ^{\circ}\text{C}$, $\lambda = 950 \, \text{nm}$) **Characteristics**

Bezeichnung Parameter	Symbol Symbol	Wert Value		Einheit Unit	
		SFH 314	SFH 314 FA		
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	$\lambda_{\text{S max}}$	850	870	nm	
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von $S_{\rm max}$ Spectral range of sensitivity $S = 10\%$ of $S_{\rm max}$	λ	460 1080	740 1080	nm	
Bestrahlungsempfindliche Fläche Radiant sensitive area	A	0.55	0.55	mm ²	
Abmessungen der Chipfläche Dimensions of chip area	$L \times B$ $L \times W$	1 × 1	1 × 1	mm × mm	
Halbwinkel Half angle	φ	± 40	± 40	Grad deg.	
Kapazität, V_{CE} = 5 V, f = 1 MHz, E = 0 Capacitance	C_{CE}	10	10	pF	
Dunkelstrom Dark current $V_{\rm CE}$ = 10 V, E = 0	$I_{\sf CEO}$	3 (≤ 200)	3 (≤ 200)	nA	



Die Fototransistoren werden nach ihrer Fotoempfindlichkeit gruppiert und mit arabischen Ziffern gekennzeichnet.

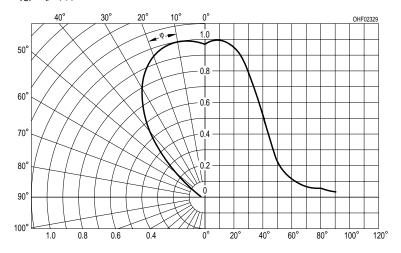
The phototransistors are grouped according to their spectral sensitivity and distinguished by arabian figures.

Bezeichnung Parameter	Symbol Symbol	Wert Value				Einheit Unit
		-1	-2	-3	-4	
Fotostrom, $\lambda = 950 \text{ nm}$ Photocurrent						
$E_{\rm e}$ = 0.5 mW/cm ² , $V_{\rm CE}$ = 5 V SFH 314:	I_{PCE}	0.63 1.25	1 2	1.6 3.2	≥ 2.5	mA
$E_{\rm v}$ = 1000 lx, Normlicht/ standard light A, $V_{\rm CE}$ = 5 V	I_{PCE}	3.4	5.4	8.6	13.5	mA
Anstiegszeit/Abfallzeit Rise and fall time $I_{\rm C}$ = 1 mA, $V_{\rm CC}$ = 5 V, $R_{\rm L}$ = 1 k Ω	$t_{\rm r},\ t_{\rm f}$	8	10	12	14	μѕ
Kollektor-Emitter- Sättigungsspannung Collector-emitter saturation	V_{CEsat}	150	150	150	150	mV
voltage $I_{\rm C} = I_{\rm PCEmin}^{1)} \times 0.3$, $E_{\rm e} = 0.5 \ {\rm mW/cm^2}$						

 $^{^{\}rm 1)}~~I_{\rm PCEmin}$ ist der minimale Fotostrom der jeweiligen Gruppe.

Directional Characteristics

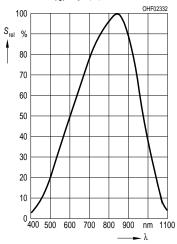
$$S_{\mathsf{rel}} = f(\varphi)$$



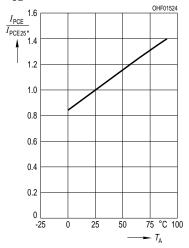
 $^{^{1)}}$ $I_{
m PCEmin}$ is the min. photocurrent of the specified group.

 $T_{\rm A}$ = 25 °C, λ = 950 nm

Relative Spectral Sensitivity, SFH 314 $S_{\text{rel}} = f(\lambda)$

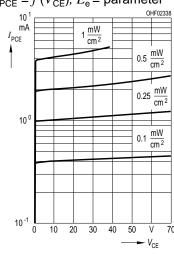


$\begin{aligned} & \textbf{Photocurrent} \ I_{\text{PCE}} = f \ (T_{\text{A}}), \\ & V_{\text{CE}} = 5 \ \text{V, normalized to 25 °C} \end{aligned}$

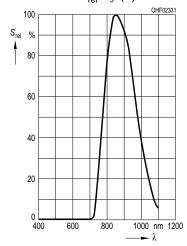


Photocurrent

 $I_{\text{PCE}} = f(V_{\text{CE}}), E_{\text{e}} = \text{parameter}$

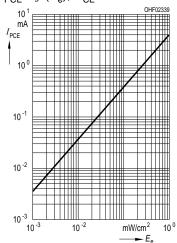


Relative Spectral Sensitivity, SFH 314 FA $S_{\text{rel}} = f(\lambda)$



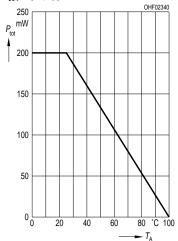
Photocurrent

$$I_{\text{PCE}} = f(E_{\text{e}}), V_{\text{CE}} = 5 \text{ V}$$



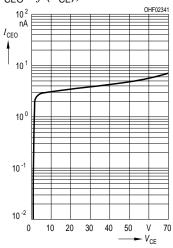
Total Power Dissipation

 $P_{\text{tot}} = f(T_{\text{A}})$



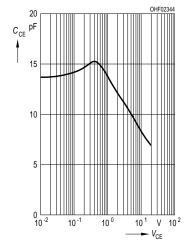
Dark Current

 $I_{\text{CEO}} = f(V_{\text{CE}}), E = 0$



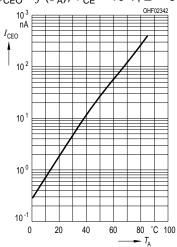
Collector-Emitter Capacitance

 $C_{CE} = f(V_{CE}), f = 1 \text{ MHz}$

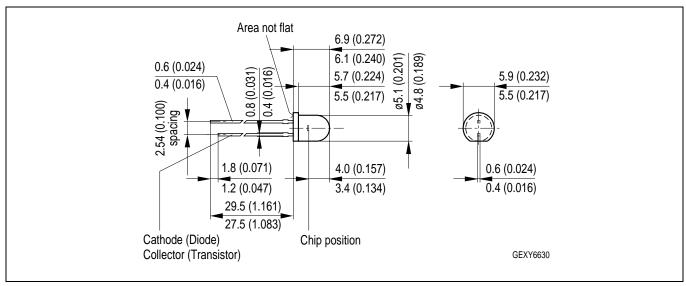


Dark Current

 $I_{\mathrm{CEO}} = f\left(T_{\mathrm{A}}\right), \; V_{\mathrm{CE}} = 10 \; \mathrm{V}, \; E = 0$



Maßzeichnung Package Outlines

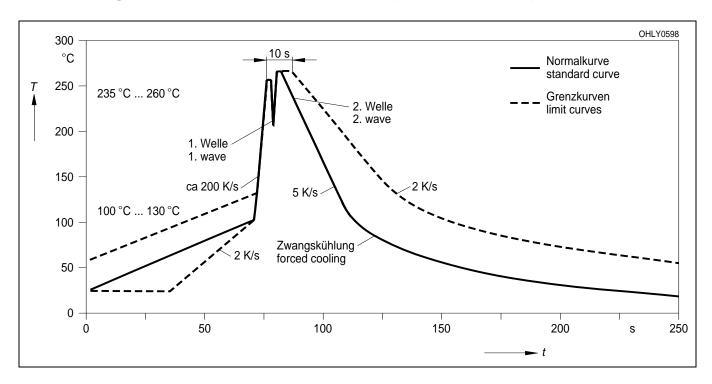


Maße in mm (inch) / Dimensions in mm (inch).



Lötbedingungen **Soldering Conditions** Wellenlöten (TTW) TTW Soldering

(nach CECC 00802) (acc. to CECC 00802)



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